INTEGRATED CIRCUITS
UNITRODE

UC1856
UC2856
UC3856

Improved Current Mode PWM Controller

FEATURES

- Pin-for-Pin Compatible With the UC3846
- 65ns Typical Delay From Shutdown to Outputs, and 50ns Typical Delay From Sync to Outputs
- Improved Current Sense Amplifier With Reduced Noise Sensitivity
- Differential Current Sense with 3V Common Mode Range
- Trimmed Oscillator Discharge Current for Accurate Deadband Control
- Accurate 1V Shutdown Threshold
- High Current Dual Totem Pole Outputs (1.5A peak)
- TTL Compatible Oscillator SYNC Pin Thresholds
- 4kV ESD Protection

DESCRIPTION

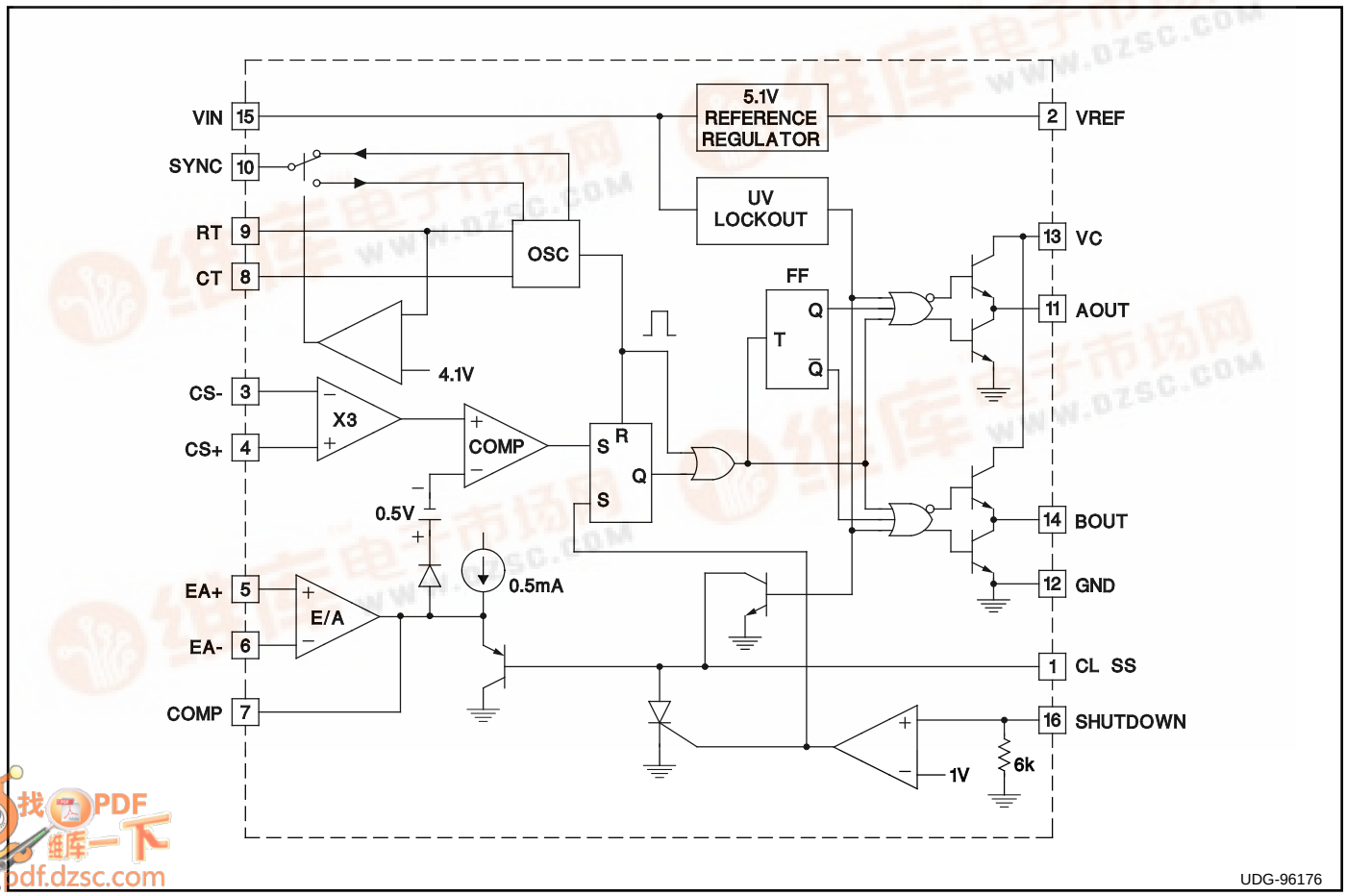
The UC3856 is a high performance version of the popular UC3846 series of current mode controllers, and is intended for both design upgrades and new applications where speed and accuracy are important. All input to output delays have been minimized, and the current sense output is slew rate limited to reduce noise sensitivity. Fast 1.5A peak output stages have been added to allow rapid switching of power FETs.

A low impedance TTL compatible sync output has been implemented with a tri-state function when used as a sync input.

Internal chip grounding has been improved to minimize internal "noise" caused when driving large capacitive loads. This, in conjunction with the improved differential current sense amplifier results in enhanced noise immunity.

Other features include a trimmed oscillator current (8%) for accurate frequency and dead time control; a 1V, 5% shutdown threshold; and 4kV minimum ESD protection on all pins.

BLOCK DIAGRAM

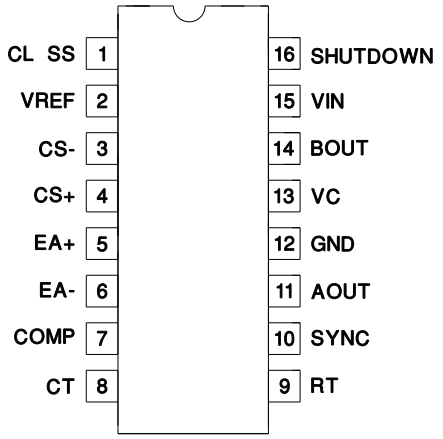


ABSOLUTE MAXIMUM RATINGS

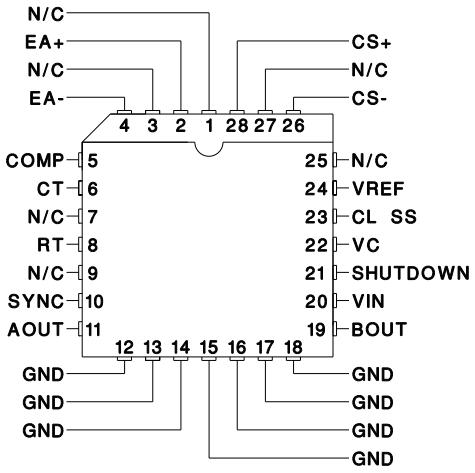
Supply Voltage .....+40V
Collector Supply Voltage .....+40V
Output Current, Source or Sink
DC.....0.5A
Pulse (0.5µs).....2.0A
Error Amp Inputs.....–0.3V to +V_{IN}
Shutdown Input.....–0.3V to +10V
Current Sense Inputs.....–0.3V to +3V
SYNC Output Current.....±10mA
Error Amplifier Output Current .....–5mA
Soft Start Sink Current.....50mA
Oscillator Charging Current 5mA
Power Dissipation at T_A = 25°C (Note 2).....1000mW
Power Dissipation at T_C = 25°C (Note 2) 2000mW
Junction Temperature.....–55°C to +150°C
Storage Temperature Range .....–65°C to +150°C
Lead Temperature (Soldering, 10 sec.) .....+300°C
All voltages are with respect to Ground. Currents are positive into, negative out of the specified terminal. Consult packaging section of databook for thermal limitations and considerations of package.

CONNECTION DIAGRAMS

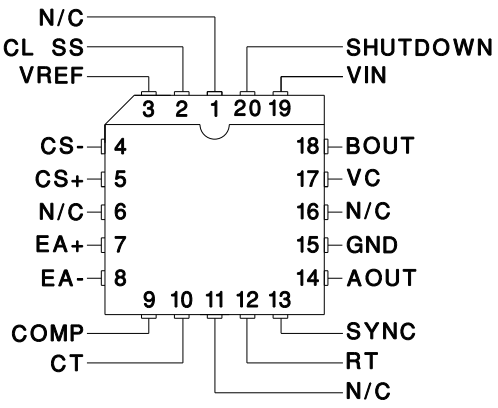
DIL–16, SOIC-16 (Top View)
J or N, DW PACKAGE



PLCC-28 (Top View)
QP PACKAGE



PLCC-20 (Top View)
Q PACKAGE



ELECTRICAL CHARACTERISTICS

Unless otherwise stated, these specifications apply for T_A = –55°C to +125°C for UC1856; – 40°C to +85°C for the UC2856; and 0°C to +70°C for the UC3856, VIN = 15V, RT = 10k, CT = 1nF, T_A = T_J.

PARAMETER	TEST CONDITIONS	UC1856/UC2856			UC3856			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
Reference Section								
Output Voltage	T_J = 25°C, Io = 1mA	5.05	5.10	5.15	5.00	5.10	5.20	V
Line Regulation	VIN = 8V to 40V			20			20	mV
Load Regulation	Io = –1mA to –10mA			15			15	mV
Total Output Variation	Line, Load, and Temperature	5.00		5.20	4.95		5.25	V
Output Noise Voltage	10Hz < f < 10kHz, T_J = 25°C		50			50		µV
Long Term Stability	T_J = 125°C, 1000 Hrs (Note 2)		5	25		5	25	mV
Short Circuit Current	VREF = 0V	–25	–45	–65	–25	–45	–65	mA
Oscillator Section								
Initial Accuracy	T_J = 25°C	180	200	220	180	200	220	kHz
	Over Operating Range	170		230	170		230	kHz

ELECTRICAL CHARACTERISTICS (cont.) Unless otherwise stated, these specifications apply for T_A = –55°C to +125°C for UC1856; – 40°C to +85°C for the UC2856; and 0°C to +70°C for the UC3856, VIN = 15V, RT = 10k, CT = 1nF, $T_A = T_J$.

PARAMETER	TEST CONDITIONS	UC1856/UC2856			UC3856			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
Oscillator Section (cont.)								
Voltage Stability	VIN = 8V to 40V			2			2	%
Discharge Current	T_J = 25°C, V_{CT} = 2V	7.5	8.0	8.8	7.5	8.0	8.8	mA
	V_{CT} = 2V	6.7	8.0	8.8	6.7	8.0	8.8	mA
Sync Output High Level	Io = –1mA	2.4	3.6		2.4	3.6		V
Sync Output Low Level	Io = +1mA		0.2	0.4		0.2	0.4	V
Sync Input High Level	CT = 0V, RT = VREF	2.0	1.5		2.0	1.5		V
Sync Input Low Level	CT = 0V, RT = VREF		1.5	0.8		1.5	0.8	V
Sync Input Current	CT = 0V, RT = VREF V_{SYNC} = 5V		1	10		1	10	µA
Sync Delay to Outputs	CT = 0V, RT = VREF V_{SYNC} = 0.8V to 2V		50	100		50	100	ns
Error Amplifier Section								
Input Offset Voltage	V_{CM} = 2V			5			10	mV
Input Bias Current				–1			–1	µA
Input Offset Current				500			500	nA
Common Mode Range	VIN = 8V to 40V	0		VIN – 2	0		VIN – 2	V
Open Loop Gain	Vo = 1.2V to 3V	80	100		80	100		dB
Unity Gain Bandwidth	T_J = 25°C	1	1.5		1	1.5		MHz
CMRR	V_{CM} = 0V to 38V, VIN = 40V	75	100		75	100		dB
PSRR	VIN = 8V to 40V	80	100		80	100		dB
Output Sink Current	V_{ID} = –15mV, V_{COMP} = 1.2V	5	10		5	10		mA
Output Source Current	V_{ID} = 15mV, V_{COMP} = 2.5V	–0.4	–0.5		–0.4	–0.5		mA
Output High Level	V_{ID} = 50mV, R_L (COMP) = 15k	4.3	4.6	4.9	4.3	4.6	4.9	V
Output Low Level	V_{ID} = –50mV, R_L (COMP) = 15k		0.7	1		0.7	1	V
Current Sense Amplifier Section								
Amplifier Gain	$V_{CS–}$ = 0V, CL SS Open (Notes 3,4)	2.5	2.75	3.0	2.5	2.75	3.0	V/V
Maximum Differential Input Signal ($V_{CS+} – V_{cs-}$)	CL SS Open (Note 3) R_L (COMP) = 15k	1.1	1.2		1.1	1.2		V
Input Offset Voltage	$V_{CL\ SS}$ = 0.5V COMP Open (Note 3)		5	35		5	35	mV
CMRR	V_{CM} = 0V to 3V	60			60			dB
PSRR	VIN = 8V to 40V	60			60			dB
Input Bias Current	$V_{CL\ SS}$ = 0.5V, COMP Open (Note 3)			–1	–3	–1	–3	µA
Input Offset Current	$V_{CL\ SS}$ = 0.5V, COMP Open (Note 3)			1			1	mA
Input Common Mode Range		0		3	0		3	V
Delay to Outputs	V_{EA+} = VREF, EA– = 0V CS+ – CS– = 0V to 1.5V		120	250		120	250	ns
Current Limit Adjust Section								
Current Limit Offset	V_{CS-} = 0V V_{CS+} = 0V, COMP = Open (Note 3)	0.43	0.5	0.57	0.43	0.5	0.57	V
Input Bias Current	V_{EA+} = VREF, $V_{EA–}$ = 0V		–10	–30		–10	–30	µA
Shutdown Terminal Section								
Threshold Voltage		0.95	1.00	1.05	0.95	1.00	1.05	V
Input Voltage Range		0		5	0		5	V

ELECTRICAL CHARACTERISTICS (cont.) Unless otherwise stated, these specifications apply for T_A = –55°C to +125°C for UC1856; – 40°C to +85°C for the UC2856; and 0°C to +70°C for the UC3856, VIN = 15V, RT = 10k, CT = 1nF, $T_A = T_J$.

PARAMETER	TEST CONDITIONS	UC1856/UC2856			UC3856			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
Shutdown Terminal Section (cont.)								
Minimum Latching Current ($I_{CL\ SS}$)	(Note 5)	3	1.5		3	1.5		mA
Maximum Non-Latching Current ($I_{CL\ SS}$)	(Note 6)		1.5	0.8		1.5	0.8	mA
Delay to Outputs	$V_{SHUTDOWN}$ = 0 to 1.3V		65	110		65	110	ns
Output Section								
Collector-Emitter Voltage		40			40			V
Off-State Bias Current	VC = 40V			250			250	µA
Output Low Level	I_{OUT} = 20mA		0.1	0.5		0.1	0.5	V
	I_{OUT} = 200mA		0.5	2.6		0.5	2.6	V
Output High Level	I_{OUT} = –20mA	12.5	13.2		12.5	13.2		V
	I_{OUT} = –200mA	12	13.1		12	13.1		V
Rise Time	C1 = 1nF		40	80		40	80	ns
Fall Time	C1 = 1nF		40	80		40	80	ns
UVLO Low Saturation	VIN = 0V, I_{OUT} = 20mA		0.8	1.5		0.8	1.5	V
PWM Section								
Maximum Duty Cycle		45	47	50	45	47	50	%
Minimum Duty Cycle				0			0	%
Undervoltage Lockout Section								
Startup Threshold			7.7	8.0		7.7	8.0	V
Threshold Hysterisis			0.7			0.7		V
Total Standby Current								
Supply Current			18	23		18	23	mA

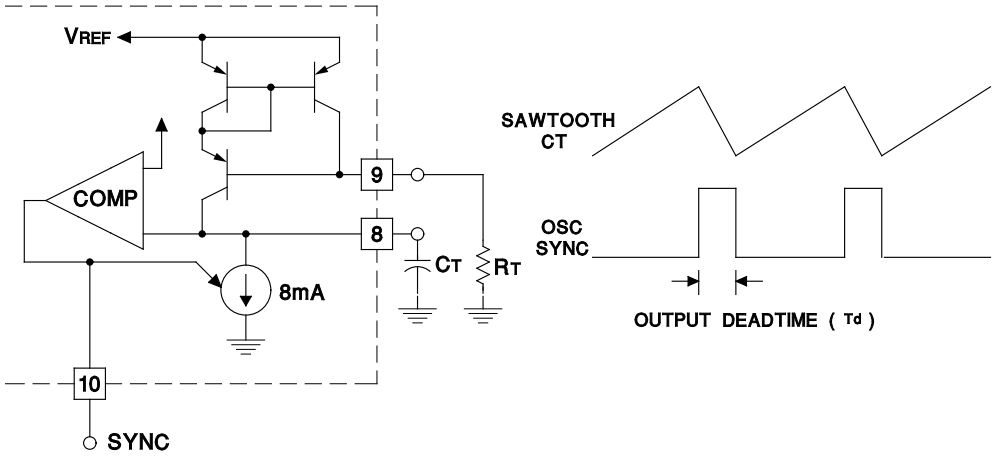
Note 1: All voltages are with respect to GND. Currents are positive into, negative out of the specified terminal.
Note 2: This parameter, although guaranteed over the recommended operating conditions is not 100% tested in production.
Note 3: Parameter measured at trip point of latch with $V_{EA}+ = VREF$, $V_{EA}- = 0V$.
Note 4: Amplifier gain defined as:

$$G = \frac{\Delta V_{COMP}}{\Delta V_{CS}+}; \qquad \Delta V_{CS}- = 0V \text{ to } 1.0V$$

Note 5: Current into CL SS guaranteed to latch circuit into shutdown state.
Note 6: Current into CL SS guaranteed not to latch circuit into shutdown state.

APPLICATIONS INFORMATION

Oscillator Circuit



Output deadtime is determined by size of the external capacitor, C_T, according to the formula: $Td = \frac{2C_T}{8mA - \frac{3.6}{R_T}}$

For large values of R_T: $Td = 250C_T$

Oscillator frequency is approximated by the formula: $f_T = \frac{2}{R_T C_T}$

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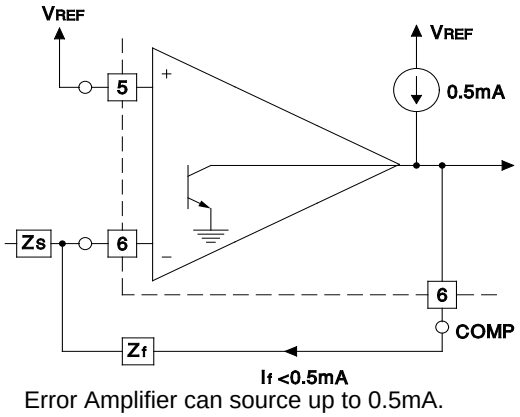
Error Amplifier Output Configuration



Error Amplifier can source up to 0.5mA.

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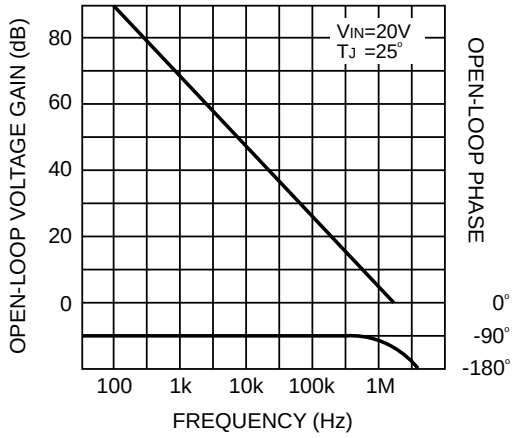
Error Amplifier Gain and Phase vs Frequency



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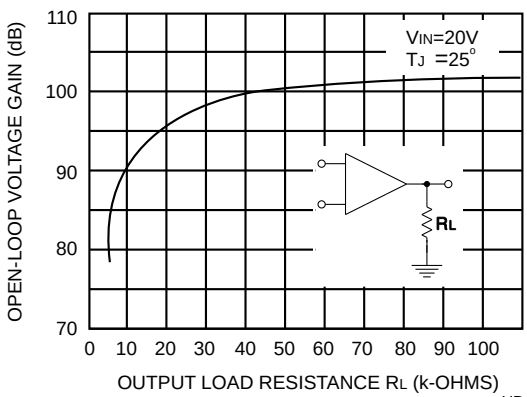
Error Amplifier Open-Loop D.C. Gain vs Load Resistance



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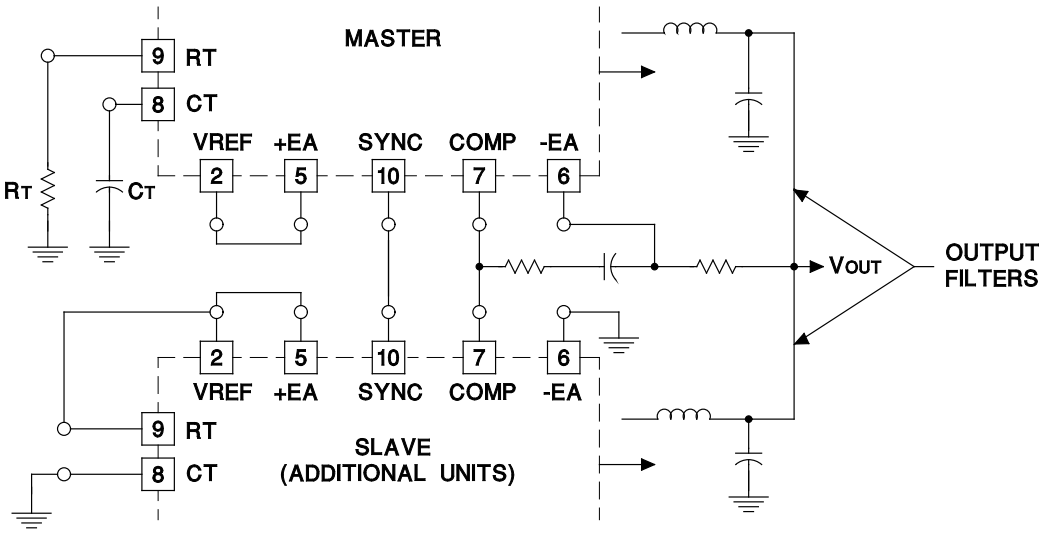
APPLICATIONS INFORMATION (cont.)

Parallel Operation



Slaving allows parallel operation of two or more units with equal current sharing.

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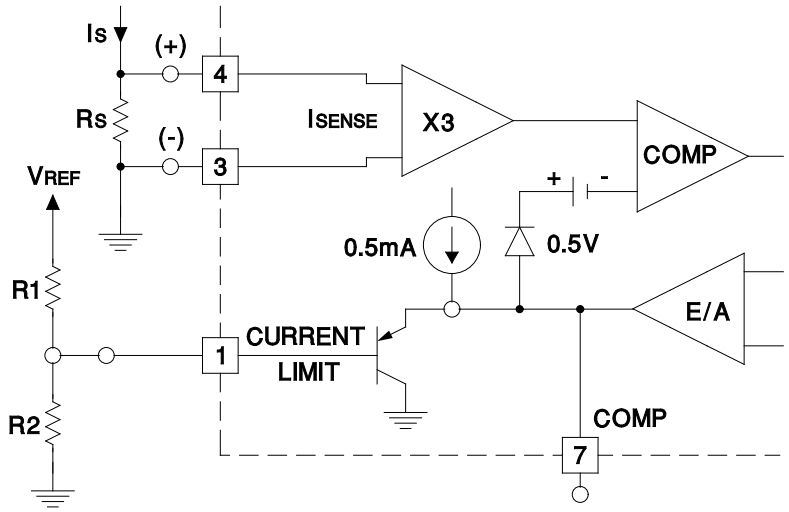
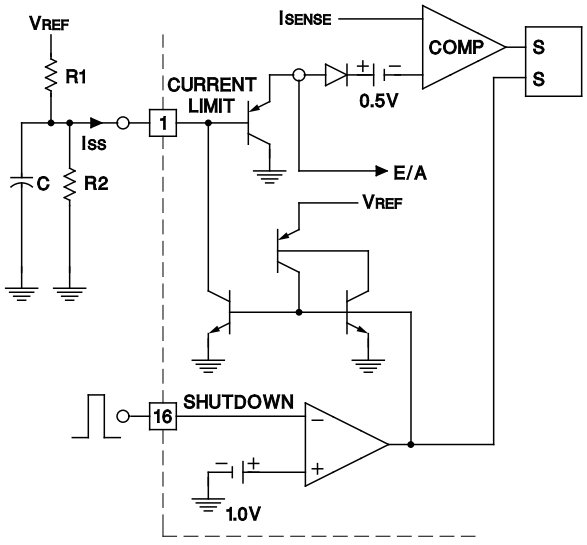
Pulse by Pulse Current Limiting



Peak current (Is) is determined by the formula: $Is = \frac{\left(\frac{R2\ V_{REF}}{R1 + R2}\right) - 0.5}{3R_S}$

UDG-96182

APPLICATIONS DATA (cont.)



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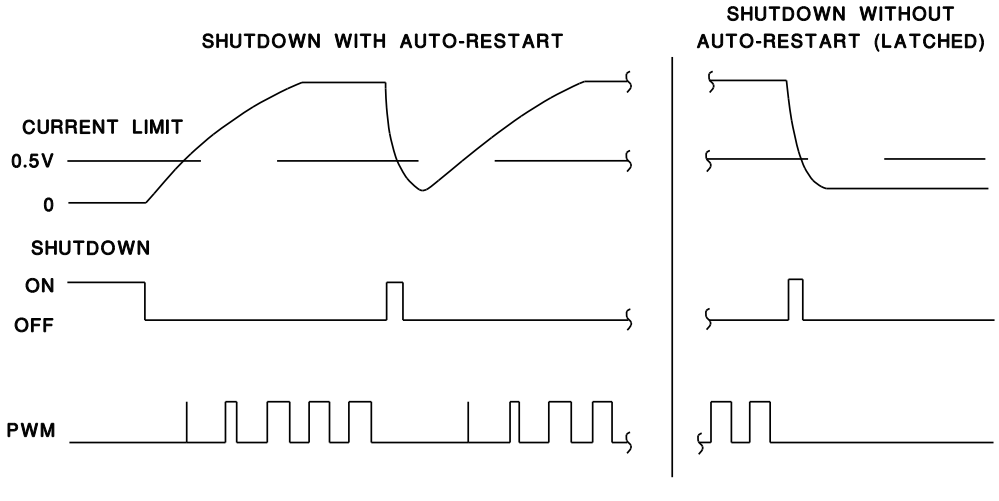

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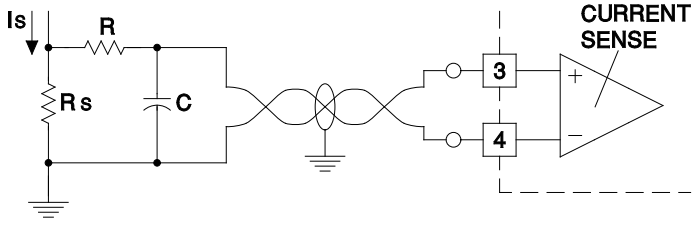
If $\frac{V_{REF}}{R1} < 0.8mA$, the shutdown latch will commutate when $I_{SS} = 0.8mA$ and a restart cycle will be initiated.

If $\frac{V_{REF}}{R1} < 3mA$, the device will latch off until power is recycled.

Current Sense Amplifier Connections



A small RC filter may be required in some applications to reduce switch transients. Differential input allows remote, noise sensing.

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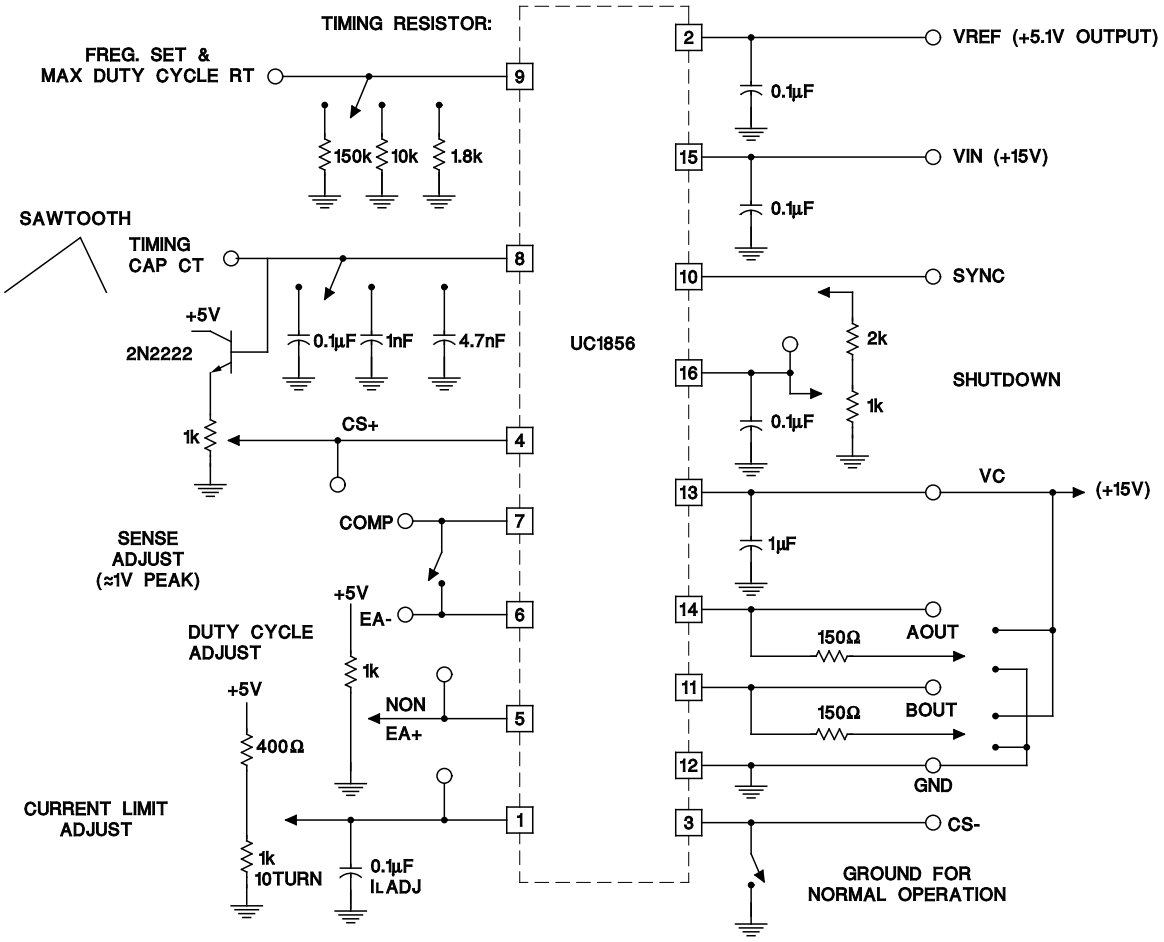
APPLICATIONS INFORMATION (cont.)

UC1856 Open Loop Test Circuit



- BYPASS CAPS SHOULD BE LOW ESR & ESL TYPE
- SHORT E/A- & COMP FOR UNITY GAIN TESTING

THE USE OF A GROUND PLANE IS HIGHLY RECOMMENDED

UDG-96186

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